

# 2.3MHz, 2A Synchronous Step-Down Converter

#### **FEATURES**

- High Efficiency: Up to 95% (@3.3V<sub>OUT</sub>)
- . 2.3MHz Co Frequency Operation
- . 2A Output Current
- . No Schottky Diode Required
- 2.7V to 5.5V Input Voltage Range
- Output Voltage as Low as 0.6V
- . PFM Mode for High Efficiency in Light Load
- . 100% Duty Cycle in Dropout Operation
- . Low Quiescent Current: 40µA
- Short Circuit Protection
- . Thermal Fault Protection
- . Inrush Current Limit and Soft Start
- . Input over voltage protection (OVP)
- . <1µA Shutdown Current
- SOT23-5 Package

#### **APPLICATIONS**

- . Set Top Box
- Wireless and DSL Modems
- PDAs
- Portable Instruments
- . Digital Still and Video Cameras
- PC Cards

#### **GENERAL DESCRIPTION**

The TMI3112H is a 2.3MHz constant frequency, current mode step-down converter. It is ideal for portable equipment requiring very high current up to 2A from single-cell Lithium-ion batteries while still achieving over 95% efficiency during peak load conditions with 5V input and 3.3V output application. The TMI3112H also can run at 100% duty cycle for low dropout operation, extending battery life in portable systems while light load operation provides very low output ripple for noise sensitive applications. The TMI3112H can supply up to 2A output load current from 2.7V to 5.5V input voltage and the output voltage can be regulated as low as 0.6V. The high switching frequency minimizes the size of external components while keeping switching losses low. The internal slope compensation setting allows the device to operate with smaller inductor values to optimize size and provide efficient operation. The TMI3112H is offered in a 5-pin, SOT package, and is available in an adjustable version. This device offers two operation modes, PWM control and PFM Mode switching control, which allows a high efficiency over the wider range of the load.

#### TYPICAL APPILCATION

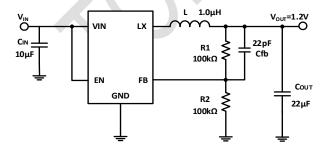
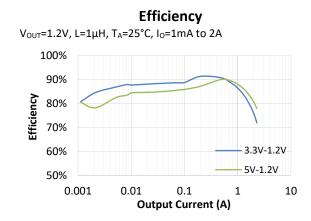


Figure 1. Basic Application Circuit



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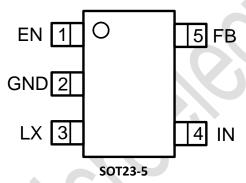
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# ABSOLUTE MAXIMUM RATINGS (Note 1)

Parameter	Value	Unit
Input Supply Voltage	-0.3~6.5	V
LX Voltages	-0.3~6.5	٧
EN, FB Voltage	-0.3~6.5	٧
LX Voltage (<10ns transient)	-2.5~7	٧
LX Voltage (<5ns transient)	-3.5~7.5	٧
Storage Temperature Range	-65~150	°C
Junction Temperature (Note2)	-40~155	°C
Power Dissipation	650	mW
Lead Temperature (Soldering,10s)	260	°C

# PACKAGE/ORDER INFORMATION



Top Mark: T2HXXX (T2H: Device Code, XXX: Inside Code)

Part Number	Package	Top mark	Quantity/ Reel
TMI3112H	TMI3112H SOT23-5		3000

TMI3112H devices are Pb-free and RoHS compliant.



# **PIN DESCRIPTION**

Pin	Name	Function			
1	EN	Chip Enable Pin. Drive EN above 1.5V to turn on the part. Drive EN below 0.4V to turn			
1	EIN	it off. Do not leave EN floating.			
2	GND	Ground pin.			
2	137	Power Switch Output. It is the switch node connection to Inductor. This pin connects			
3	LX	to the drains of the internal P-ch and N-ch MOSFET switches.			
4	IN	Power supply input pin.			
5	FB	Output Voltage Feedback Pin.			

# **ESD RATING**

Items	Description	Value	Unit
V <sub>ESD_HBM</sub>	Human Body Model for all pins	±2000	V
V <sub>ESD_CDM</sub>	Charge Device Model for all pins	±1000	V

# **JEDEC specification JS-001**

# RECOMMENDED OPERATING CONDITIONS

Items	Description	Min	Max	Unit
Voltage Range	IN	2.7	5.5	V
T <sub>J</sub>	Operating Junction Temperature Range	-40	125	°C

# THERMAL RESISITANCE (Note 3)

Items	Description	Value	Unit
$\theta_{JA}$	Junction-to-ambient thermal resistance	200	°C/W
θ <sub>JC</sub>	Junction-to-case thermal resistance	60	°C/W





# **ELECTRICAL CHARACTERISTICS**

# (VIN=VEN=3.6V, VOUT=1.8V, TA = 25°C, unless otherwise noted.)

Parameter	Test Conditions	Min	Тур	Max	Unit
Input Voltage Range		2.7		5.5	V
Input OVP Threshold	V <sub>IN</sub> rising	5.75	5.85	6.1	V
UVLO Threshold	V <sub>IN</sub> rising		2.4		V
UVLO Hysteresis			0.4	1	V
Quiescent Current	V <sub>EN</sub> =2.0V, I <sub>OUT</sub> =0, V <sub>FB</sub> =V <sub>REF</sub> *105%		40	100	μΑ
Shutdown Current	V <sub>EN</sub> =0V		0.1	1.0	μΑ
Feedback Voltage Accuracy	T <sub>A</sub> = 25°C, PWM Operation	0.588	0.600	0.612	V
Oscillation Francisco	V <sub>OUT</sub> =100%		2.3		MHz
Oscillation Frequency	V <sub>OUT</sub> =0V		350		kHz
On Resistance of PMOS	I <sub>LX</sub> =100mA		120		mΩ
On Resistance of NMOS	I <sub>LX</sub> =-100mA		70		mΩ
Peak Current Limit	V <sub>IN</sub> =5V, V <sub>OUT</sub> =90%		2.7		Α
EN Rising Threshold	V <sub>IN</sub> =5V	0.9	1.15	1.4	V
EN Falling Threshold	V <sub>IN</sub> =5V	0.75	1.0	1.25	V
Soft Start Time		0.7	1.0	1.3	ms
EN Leakage Current			0.01	1.0	μΑ
LX Leakage Current	V <sub>EN</sub> =0V, V <sub>IN</sub> =V <sub>LX</sub> =5V		0.01	1.0	μΑ
Thermal Shutdown Threshold (Note 4)			160		°C
Thermal Shutdown Hysteresis (Note 4)			20		°C

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:**  $T_J$  is calculated from the ambient temperature  $T_A$  and power dissipation  $P_D$  according to the following formula:  $T_J = T_A + (P_D) \times \theta_{JA}$ .

Note 3: Measured on JESD51-7, 4-layer PCB.

Note 4: Thermal shutdown threshold and hysteresis are guaranteed by design.



#### **FUNCTION DESCRIPTION**

The TMI3112H is a high output current switch mode step-down DC-DC converter. The device operates at a fixed 2.3MHz switching frequency, and uses a slope compensated current mode architecture.

This step-down DC-DC converter can supply up to 2A output current at  $V_{IN}$ =5.0V and has an input voltage range from 2.7V to 5.5V. It minimizes external component size and optimizes efficiency at the heavy load range. The slope compensation allows the device to remain stable over a wider range of inductor values so that smaller values with lower DCR can be used to achieve higher efficiency. Only a small bypass input capacitor is required at the output.

The adjustable output voltage can be programmed with external feedback to any voltage, ranging from 0.6V to near the input voltage. It uses internal MOSFETs to achieve high efficiency and can generate very low output voltages by using an internal reference of 0.6V. At dropout operation, the converter duty cycle increases to 100% and the output voltage tracks the input voltage minus the low R<sub>DS(ON)</sub> drop of the P-channel high-side MOSFET and the inductor DCR. The internal error amplifier and compensation provides excellent transient response, load and line regulation. Internal soft start eliminates any output voltage overshoot when the enable or the input voltage is applied.

#### **FUNCTIONAL BLOCK DIAGRAM**

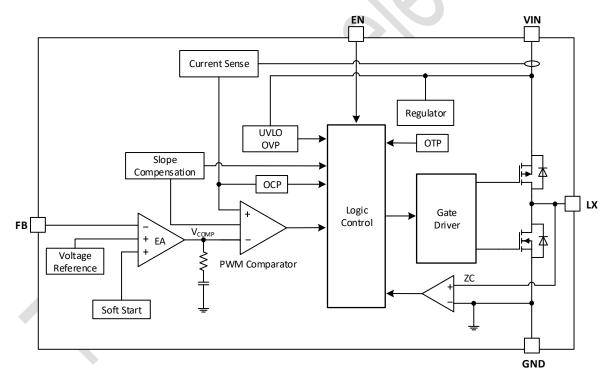
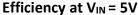


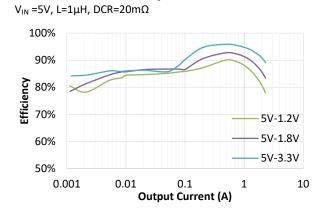
Figure 2. TMI3112H Block Diagram



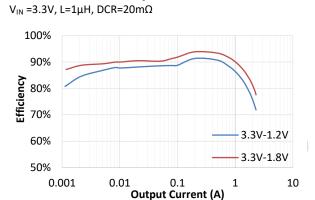
## TYPICAL PERFORMANCE CHARACTERISTICS

Test condition:  $V_{IN}=5V$ ,  $V_{OUT}=1.2V$ ,  $L=1\mu H$ ,  $T_A=25$ °C, unless other noted.



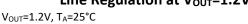


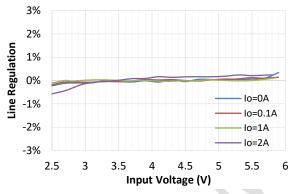
# Efficiency at V<sub>IN</sub> = 3.3V



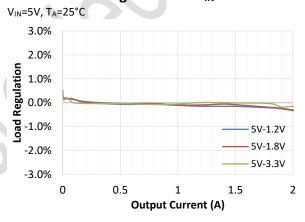
#### Line Regulation at Vout=1.2V

3% 2% 1%



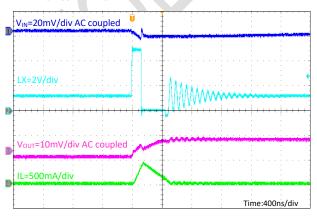


# Load Regulation at V<sub>IN</sub> = 5V

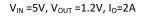


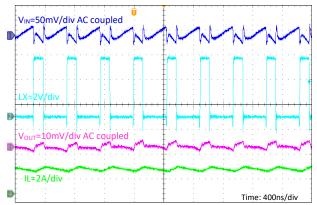
## **Steady State Operation**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V, No Load



### **Steady State Operation**



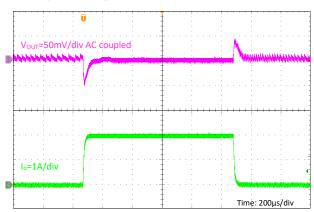




# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

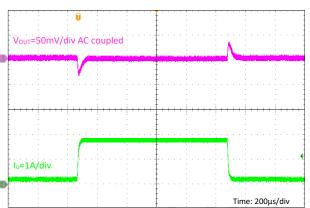
#### **Load Transient**

 $V_{\text{IN}}$  =5V,  $V_{\text{OUT}}$  =1.2V,  $I_{\text{O}}$  = 0A to 2A



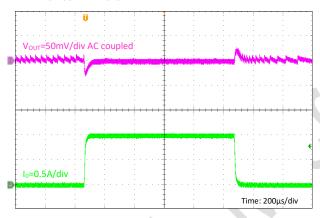
#### **Load Transient**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V,  $I_{O}$  = 0.2A to 1.8A



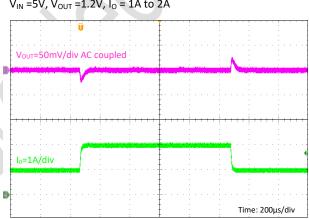
#### **Load Transient**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V,  $I_{O}$  = 0A to 1A



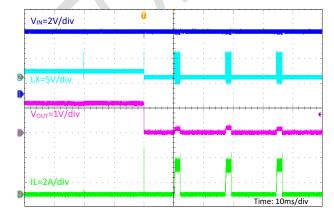
# **Load Transient**

 $V_{IN} = 5V$ ,  $V_{OUT} = 1.2V$ ,  $I_{O} = 1A$  to 2A



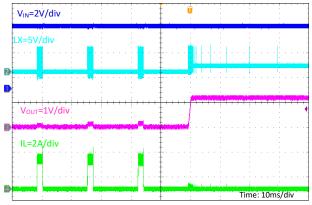
## **Output Short Entry**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V,  $I_O$  = No Load



# **Output Short Recovery**

 $V_{IN}$ =5V,  $V_{OUT}$  =1.2V,  $I_O$  = No Load



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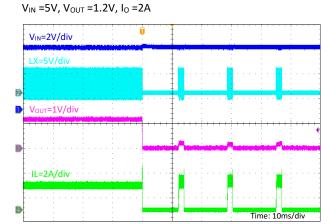
www.toll-semi.com



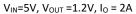
# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

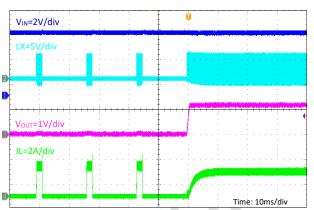
## **Output Short Entry**

#### Output Short Lift



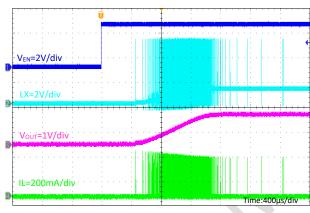
## **Output Short Recovery**





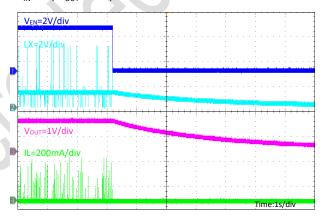
#### **EN Enable Power On**

 $V_{\text{IN}}$  =5V,  $V_{\text{OUT}}$  =1.2V, No Load



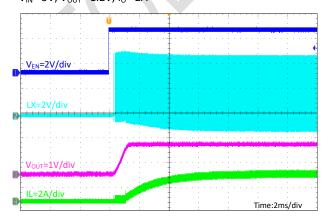
#### **EN Disable Power down**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V, No Load



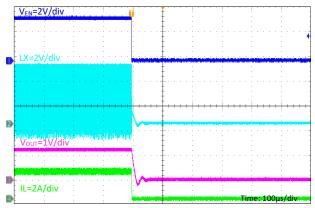
#### **EN Enable Power On**

V<sub>IN</sub> =5V, V<sub>OUT</sub> =1.2V, I<sub>O</sub> =2A



#### **EN Disable Power down**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V,  $I_{O}$  =2A

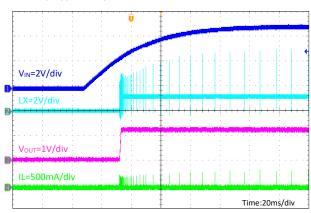




# TYPICAL PERFORMANCE CHARACTERISTICS (continued)

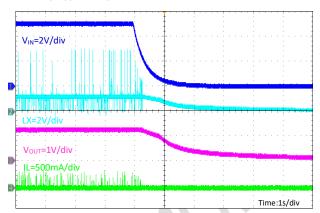
## **Input Power On**

V<sub>IN</sub> =5V, V<sub>OUT</sub> =1.2V, No Load



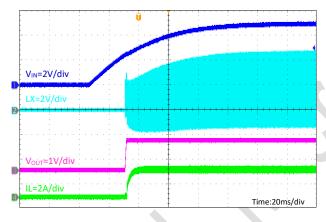
## **Input Power Down**

 $V_{\text{IN}}$  =5V,  $V_{\text{OUT}}$  =1.2V, No Load



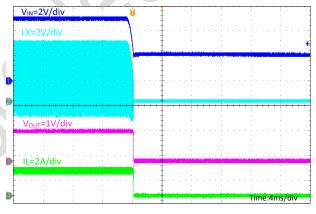
#### **Input Power On**

 $V_{IN}$  =5V,  $V_{OUT}$  =1.2V,  $I_{O}$  =2A



# **Input Power Down**

 $V_{IN} = 5V$ ,  $V_{OUT} = 1.2V$ ,  $I_{O} = 2A$ 





#### APPLICATION INFORMATION

#### **Setting the Output Voltage**

Figure 1 shows the basic application circuit for the TMI3112H. The TMI3112H can be externally programmed. Resistors R1 and R2 in Figure 1 program the output to regulate at a voltage higher than 0.6V. The external resistor sets the output voltage according to the following equation:

$$V_{OUT} = 0.6 \times (1 + \frac{R_1}{R_2})$$

$$R_1 = (V_{OUT} / 0.6 - 1) \times R_2$$

#### **Inductor Selection**

For most designs, 1µH inductance can satisfy most application conditions. Inductance value is related to inductor ripple current value, input voltage, output voltage setting and switching frequency. The inductor value can be derived from the following equation:

$$L = \frac{V_{out} \times \left(V_{\mathit{IN}} - V_{out}\right)}{V_{\mathit{IN}} \times \Delta I_{\mathit{L}} \times f_{\mathit{OSC}}}$$

Where  $\Delta I_L$  is inductor ripple current. Large value inductors result in lower ripple current and small value inductors result in high ripple current, so inductor value has effect on output voltage ripple value. DC resistance of inductor which has impact on efficiency of DC/DC converter should be taken into account when selecting the inductor.

#### **Input Capacitor Selection**

The input capacitor reduces the surge current drawn from the input and switching noise from the device. The input capacitor impedance at the switching frequency should be less than input source impedance to prevent high frequency switching current passing to the input.

A low ESR input capacitor sized for maximum RMS current must be used. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR and small temperature coefficients.

A  $10\mu F$  ceramic capacitor for most applications is sufficient. A large value may be used for improved input voltage filtering.

#### **Output Capacitor Selection**

The output capacitor is required to keep the output voltage ripple small and to ensure regulation loop stability. The output capacitor must have low impedance at the switching frequency. Ceramic capacitors with X5R or X7R dielectrics are recommended due to their low ESR and high ripple current ratings. The output ripple  $\triangle V_{OUT}$  is determined by:

$$\Delta V_{OUT} \leq \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times f_{OSC} \times L} \times \left(ESR + \frac{1}{8 \times f_{osc} \times C3}\right)$$

A 22µF ceramic can satisfy most applications.



#### **Layout Consideration**

When laying out the printed circuit board, the following checking should be used to ensure proper operation of the TMI3112H. Check the following in your layout:

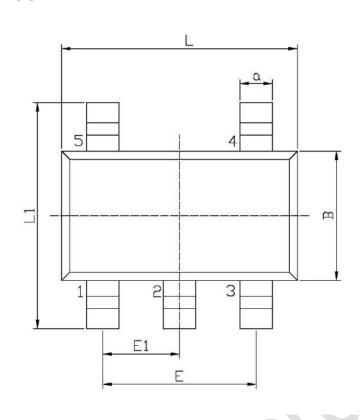
- 1. The power traces, consisting of the GND trace, the LX trace and the VIN trace should be kept short, direct and wide.
- 2. Does the (+) plates of Cin connect to Vin as closely as possible. This capacitor provides the AC current to the internal power MOSFETs.
- 3. Keep the switching node, LX, away from the sensitive VOUT node.
- 4. Keep the (-) plates of Cin and Cout as close as possible.

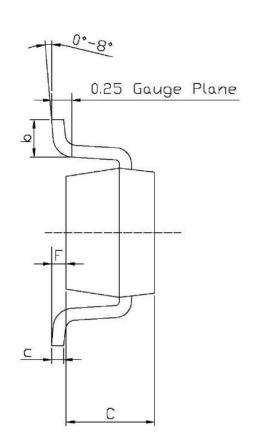




## **PACKAGE INFORMATION**

# SOT23-5





Unit: mm

Symbol	Dimensions In Millimeters			Symphol	Dimensions In Millimeters		
	Min	Тур	Max	Symbol	Min	Тур	Max
L	2.82	2.92	3.02	E1	0.85	0.95	1.05
В	1.50	1.60	1.70	а	0.35	0.425	0.50
С	0.90	1.10	1.30	С	0.10	0.15	0.20
L1	2.60	2.80	3.00	b	0.35	0.45	0.55
E	1.80	1.90	2.00	F	0	0.075	0.15

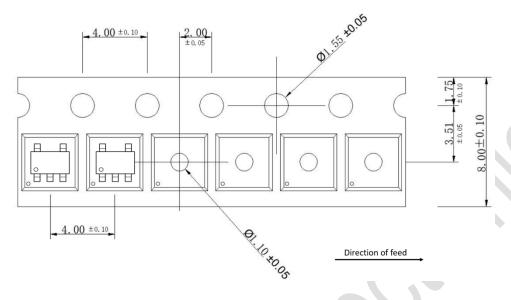
#### Note:

- 1) All dimensions are in millimeters.
- 2) Package length does not include mold flash, protrusion or gate burr.
- 3) Package width does not include inter lead flash or protrusion.
- 4) Lead popularity (bottom of leads after forming) shall be 0.10 millimeters max.
- 5) Pin 1 is lower left pin when reading top mark from left to right.

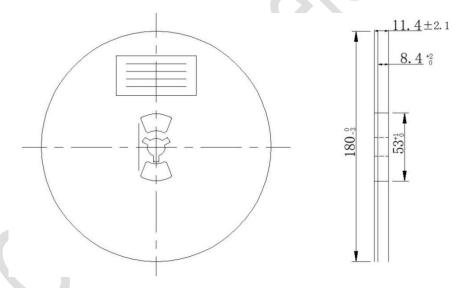


# **PACKAGE INFORMATION**

## **TAPE DIMENSIONS:**



#### **REEL DIMENSIONS:**



# Note:

- 1) All Dimensions are in Millimeter
- 2) Quantity of Units per Reel is 3000
- 3) MSL level is level 3.



# **Important Notification**

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